

1. General Description

The EM74LVC14A is a hex inverter with Schmitt-trigger inputs. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and Benefits

- Wide supply voltage range from 1.2 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- CMOS low power dissipation
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Complies with JEDEC standard:
 - JESD8-7A (1.65 V to 1.95 V)
 - JESD8-5A (2.3 V to 2.7 V)
 - JESD8-C (2.7 V to 3.6 V)
 - JESD36 (4.5 V to 5.5 V)
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001 Class 3A exceeds 6000 V
 - CDM ANSI/ESDA/JEDEC JS-002 Class C3 exceeds 2000 V
- Multiple package options

EM74LVC14A

Hex inverting Schmitt trigger with 5 V tolerant input

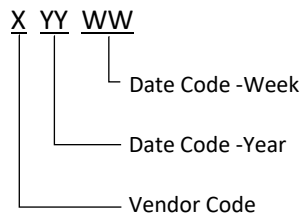
3. Ordering Information

Table 1. Ordering information

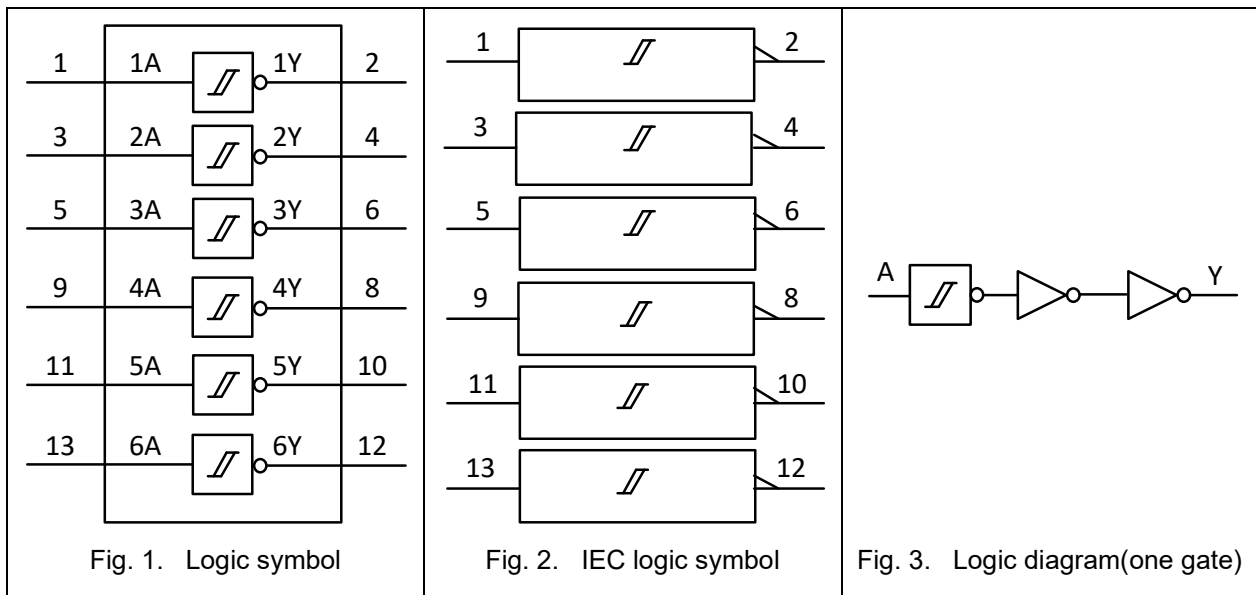
| Type number | Topside marking | Package | | |
|--------------|-----------------|-----------|---|----------|
| | | Name | Description | Quantity |
| EM74LVC14AD | LVC14A XYYWW | SOP-14L | plastic small outline package; 14 leads; body width 3.9 mm | 3000 |
| EM74LVC14APW | LVC14A XYYWW | TSSOP-14L | plastic thin shrink small outline package; 14 leads; body width 4.4 mm | 3000 |

MARKING INFORMATION

NOTE: XYYWW = Vendor Code and Date Code.

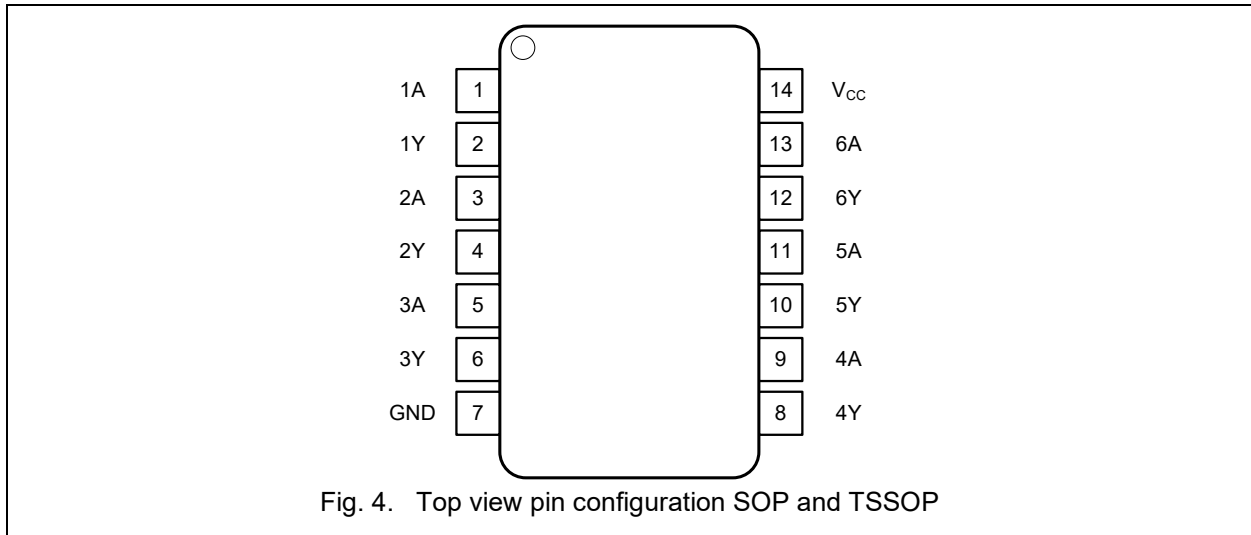


4. Function Diagram



5. Pinning Information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|------------------------|--------------------|----------------|
| 1A, 2A, 3A, 4A, 5A, 6A | 1, 3, 5, 9, 11, 13 | Data input |
| 1Y, 2Y, 3Y, 4Y, 5Y, 6Y | 2, 4, 6, 8, 10, 12 | Data output |
| GND | 7 | Ground (0V) |
| V _{CC} | 14 | Supply voltage |

6. Functional Description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level.

| Input nA | Output nY |
|----------|-----------|
| L | H |
| H | L |

7. Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Table 4. Absolute Maximum Ratings

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND.

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--|------|-----------------------|------|
| V _{CC} | supply voltage | | -0.5 | 6.5 | V |
| I _{IK} | input clamping current | V _I < 0 V | -50 | | mA |
| V _I | input voltage | [1] | -0.5 | 6.5 | V |
| I _{OK} | output clamping current | V _O > V _{CC} or V _O < 0 V | | ±50 | mA |
| V _O | output voltage | Active mode [1] | -0.5 | V _{CC} + 0.5 | V |
| | | Power-down mode; V _{CC} = 0 V [1] | -0.5 | 6.5 | V |
| I _O | output current | V _O = 0 V to V _{CC} | | ±50 | mA |
| I _{CC} | supply current | | | 100 | mA |
| I _{GND} | ground current | | -100 | | mA |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to + 125 °C | | 500 | mW |
| T _{stg} | storage temperature | | -65 | 150 | °C |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. EnergyMath does not recommend exceeding them or designing to Absolute Maximum Ratings.

Table 5. Recommended Operating Conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------|--|------|-----------------|------|
| V _{CC} | supply voltage | | 1.65 | 5.5 | V |
| | | functional | 1.2 | | V |
| V _I | input voltage | | 0 | 5.5 | V |
| V _O | output voltage | Active mode | 0 | V _{CC} | V |
| | | Power-down mode; V _{CC} = 0 V | 0 | 5.5 | V |
| T _{amb} | ambient temperature | | -40 | 125 | °C |

9. Static Characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|------------------|---------------------------|---|-----------------------|--------|------|-----------------------|------|------|
| | | | Min | Typ[1] | Max | Min | Max | |
| V _{OH} | HIGH-level output voltage | V _I = V _{T+} or V _{T-} | | | | | | |
| | | I _O = -100µA; V _{CC} = 1.65 V to 5.5 V | V _{CC} - 0.1 | | | V _{CC} - 0.1 | | V |
| | | I _O = -4 mA; V _{CC} = 1.65 V | 1.2 | | | 1.05 | | V |
| | | I _O = -8 mA; V _{CC} = 2.3 V | 1.9 | | | 1.7 | | V |
| | | I _O = -12 mA; V _{CC} = 2.7 V | 2.2 | | | 2.05 | | V |
| | | I _O = -24 mA; V _{CC} = 3.0 V | 2.4 | | | 2.25 | | V |
| | | I _O = -32 mA; V _{CC} = 4.5 V | 3.8 | | | 3.5 | | V |
| V _{OL} | LOW-level output voltage | V _I = V _{T+} or V _{T-} | | | | | | |
| | | I _O = 100µA; V _{CC} = 1.65 V to 5.5 V | | | 0.10 | | 0.10 | V |
| | | I _O = 4 mA; V _{CC} = 1.65 V | | | 0.45 | | 0.65 | V |
| | | I _O = 8 mA; V _{CC} = 2.3 V | | | 0.30 | | 0.45 | V |
| | | I _O = 12 mA; V _{CC} = 2.7 V | | | 0.40 | | 0.60 | V |
| | | I _O = 24 mA; V _{CC} = 3.0 V | | | 0.55 | | 0.80 | V |
| | | I _O = 32 mA; V _{CC} = 4.5 V | | | 0.55 | | 0.80 | V |
| I _I | input leakage current | V _I = 5.5 V or GND ; V _{CC} = 0 V to 5.5 V | | ±0.1 | ±5 | | ±20 | µA |
| I _{OFF} | power-off leakage current | V _{CC} = 0V ; V _I or V _O = 5.5 V | | ±0.1 | ±10 | | ±20 | µA |
| I _{CC} | supply current | V _I = 5.5V or GND ; I _O = 0A ; V _{CC} = 1.65V to 5.5V | | 0.03 | 10 | | 40 | µA |
| ΔI _{CC} | additional supply current | per input pin ; V _{CC} = 2.3V to 5.5V ; V _I = V _{CC} -0.6V ; I _O = 0A | | 0.8 | 500 | | 5000 | µA |
| C _I | input capacitance | V _{CC} = 3.3V ; V _I = GND to V _{CC} | | 4 | | | | pF |

 [1]All typical values are measured at V_{CC} = 3.3V and T_{amb} = 25°C.

10. Dynamic Characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|-------------|-------------------------------|--|------------------|--------|-----|-------------------|-----|------|
| | | | Min | Typ[1] | Max | Min | Max | |
| t_{pd} | propagation delay | nA to nY; see Fig. 5 [2] | | | | | | |
| | | $V_{CC} = 1.2 \text{ V}$ | | 46 | | | | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | 4 | 12.3 | 24 | 4 | 25 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | 2.5 | 7.4 | 12 | 2.5 | 13 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 1.5 | 5.7 | 8.5 | 1.5 | 9 | ns |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | 1 | 3.5 | 6 | 1 | 6.5 | ns |
| $t_{sk(o)}$ | output skew time | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ [3] | | | 1.0 | | 1.5 | ns |
| C_{PD} | power dissipation capacitance | per buffer ; $V_I = \text{GND to } V_{CC}$ [4] | | | | | | |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 12.7 | | | | pF |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 13.3 | | | | pF |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | 14.3 | | | | pF |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | | 16.5 | | | | pF |

[1] Typical values are measured at $T_{amb} = 25 \text{ °C}$ and $V_{CC} = 1.2 \text{ V}, 1.8 \text{ V}, 2.5 \text{ V}, 3.3 \text{ V}$ and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

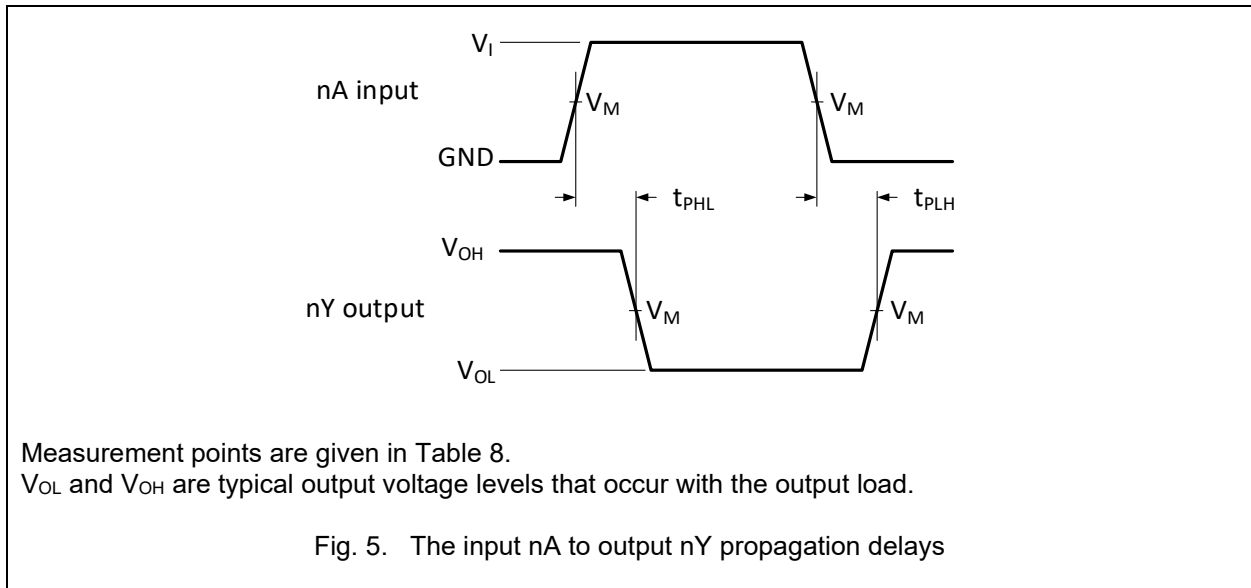
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

10.1. Waveforms and test circuit


Table 8. Measurement points

| Supply voltage | Input | Output |
|------------------|-------------|-------------|
| V_{CC} | V_M | V_M |
| 1.2 V | $0.5V_{CC}$ | $0.5V_{CC}$ |
| 1.65 V to 1.95 V | $0.5V_{CC}$ | $0.5V_{CC}$ |
| 2.3 V to 2.7 V | $0.5V_{CC}$ | $0.5V_{CC}$ |
| 3.0 V to 3.6 V | 1.5 V | 1.5 V |
| 4.5 V to 5.5 V | $0.5V_{CC}$ | $0.5V_{CC}$ |

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Hex inverting Schmitt trigger with 5 V tolerant input

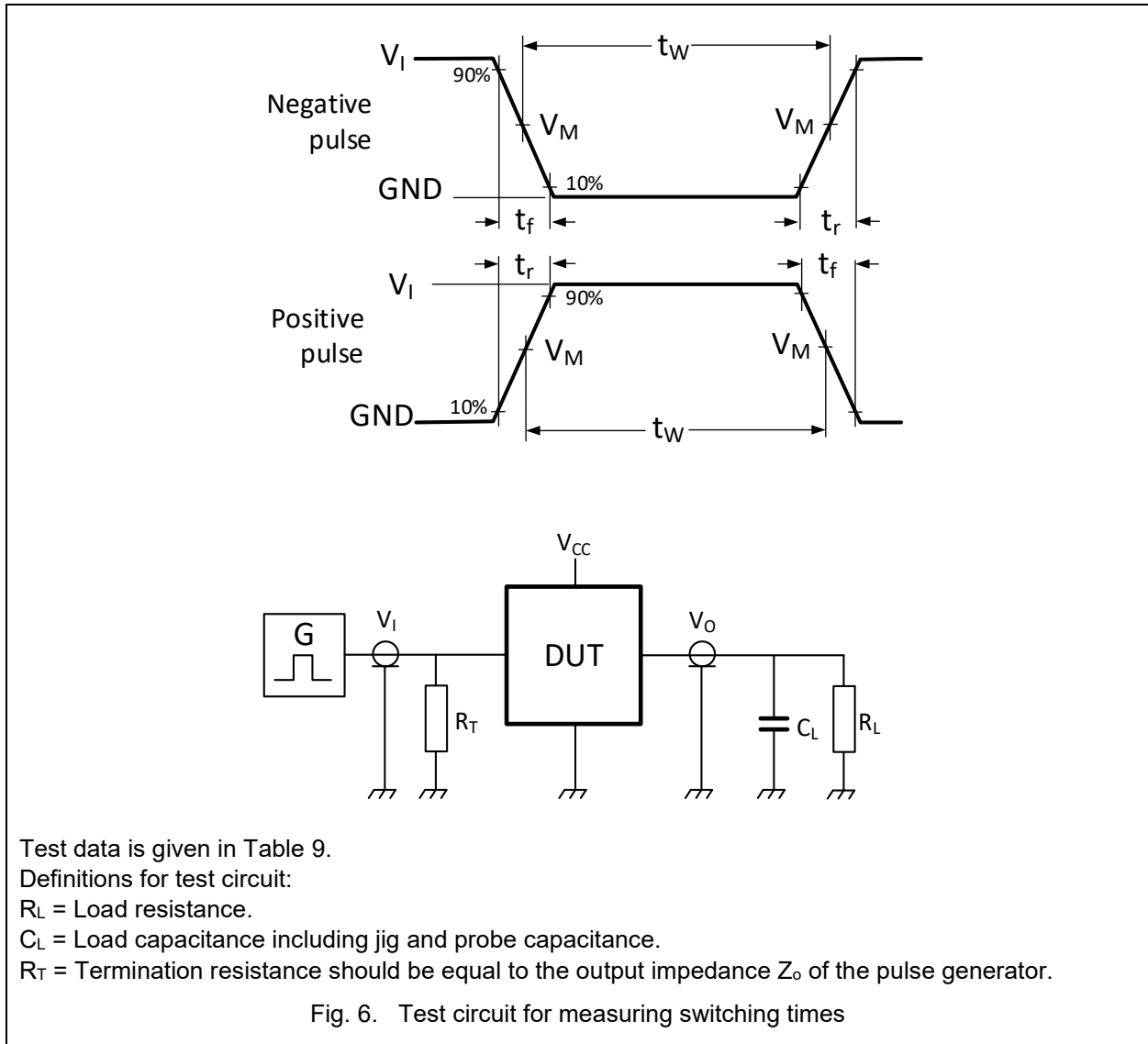


Table 9. Test data

| Supply voltage | Input | | Load | |
|------------------|----------|---------------|-------|--------------|
| V_{CC} | V_I | $t_r = t_f$ | C_L | R_L |
| 1.2 V | V_{CC} | ≤ 2.0 ns | 15 pF | 500 Ω |
| 1.65 V to 1.95 V | V_{CC} | ≤ 2.0 ns | 15 pF | 500 Ω |
| 2.3 V to 2.7 V | V_{CC} | ≤ 2.0 ns | 15 pF | 500 Ω |
| 3.0 V to 3.6 V | 3 V | ≤ 2.0 ns | 15 pF | 500 Ω |
| 4.5 V to 5.5 V | V_{CC} | ≤ 2.0 ns | 15 pF | 500 Ω |

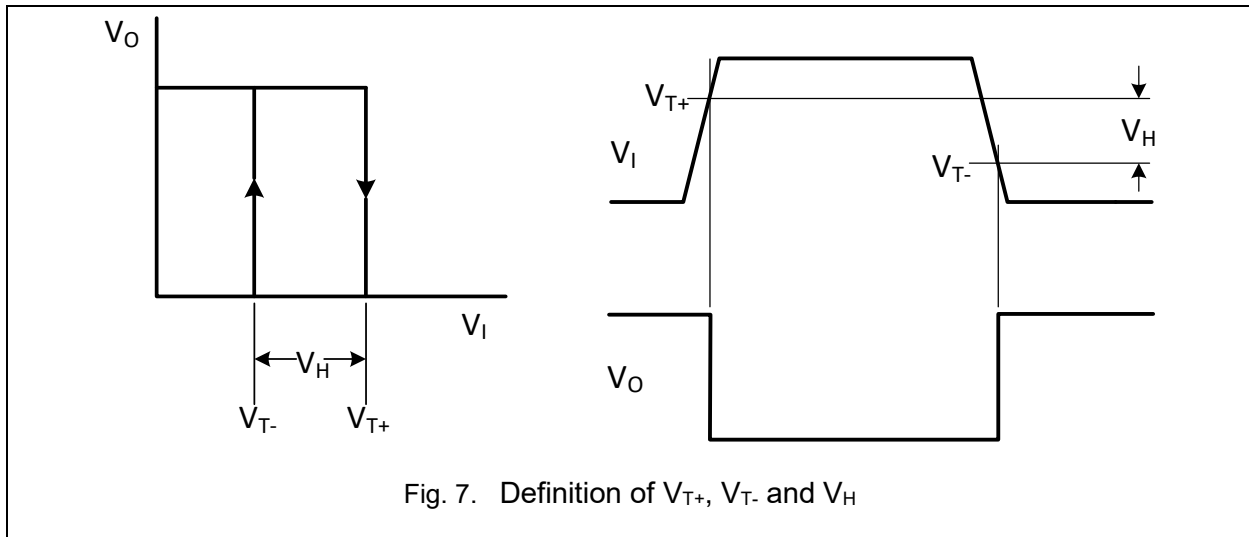
11. Transfer characteristics

Table 10. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); see Fig. 7.

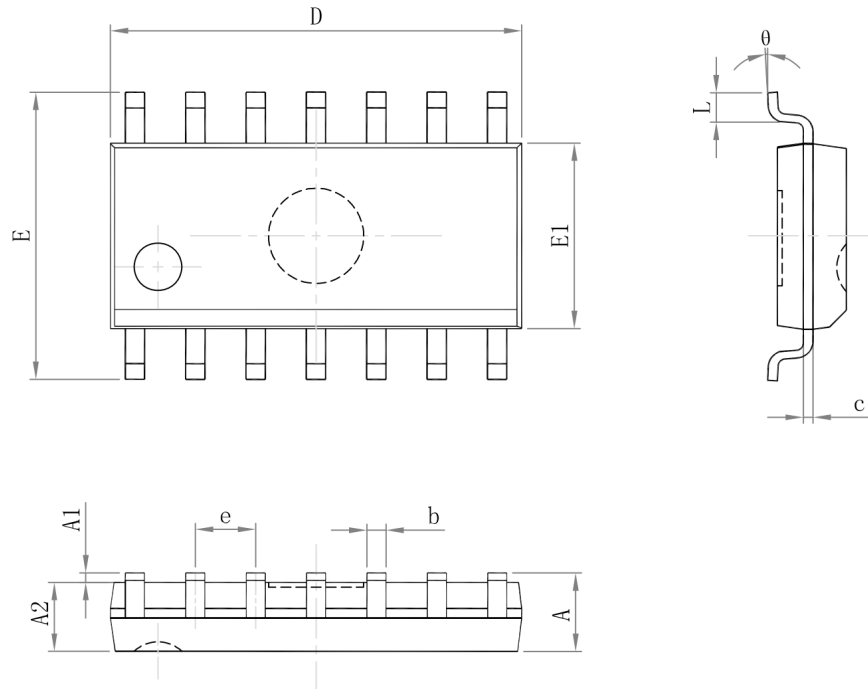
| Symbol | Parameter | Conditions | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|----------|--|--------------------------|------------------|------|-------------------|------|------|
| | | | Min | Max | Min | Max | |
| V_{T+} | positive-going threshold voltage | $V_{CC} = 1.2\text{ V}$ | 0.2 | 1.0 | 0.2 | 1.0 | V |
| | | $V_{CC} = 1.65\text{ V}$ | 0.4 | 1.3 | 0.4 | 1.3 | V |
| | | $V_{CC} = 1.95\text{ V}$ | 0.6 | 1.5 | 0.6 | 1.5 | V |
| | | $V_{CC} = 2.3\text{ V}$ | 0.8 | 1.7 | 0.8 | 1.7 | V |
| | | $V_{CC} = 2.5\text{ V}$ | 0.9 | 1.7 | 0.9 | 1.7 | V |
| | | $V_{CC} = 2.7\text{ V}$ | 1.1 | 2.0 | 1.1 | 2.0 | V |
| | | $V_{CC} = 3.0\text{ V}$ | 1.2 | 2.0 | 1.2 | 2.0 | V |
| | | $V_{CC} = 3.6\text{ V}$ | 1.2 | 2.0 | 1.2 | 2.0 | V |
| | | $V_{CC} = 4.5\text{ V}$ | 1.84 | 2.36 | 1.81 | 2.36 | V |
| | | $V_{CC} = 5.5\text{ V}$ | 2.19 | 2.79 | 2.16 | 2.79 | V |
| V_{T-} | negative-going threshold voltage | $V_{CC} = 1.2\text{ V}$ | 0.12 | 0.75 | 0.12 | 0.75 | V |
| | | $V_{CC} = 1.65\text{ V}$ | 0.15 | 0.85 | 0.15 | 0.85 | V |
| | | $V_{CC} = 1.95\text{ V}$ | 0.25 | 0.95 | 0.25 | 0.95 | V |
| | | $V_{CC} = 2.3\text{ V}$ | 0.4 | 1.1 | 0.4 | 1.1 | V |
| | | $V_{CC} = 2.5\text{ V}$ | 0.4 | 1.2 | 0.4 | 1.2 | V |
| | | $V_{CC} = 2.7\text{ V}$ | 0.8 | 1.4 | 0.8 | 1.4 | V |
| | | $V_{CC} = 3.0\text{ V}$ | 0.8 | 1.5 | 0.8 | 1.5 | V |
| | | $V_{CC} = 3.6\text{ V}$ | 0.8 | 1.5 | 0.8 | 1.5 | V |
| | | $V_{CC} = 4.5\text{ V}$ | 1.32 | 1.84 | 1.32 | 1.87 | V |
| | | $V_{CC} = 5.5\text{ V}$ | 1.58 | 2.24 | 1.58 | 2.27 | V |
| V_H | hysteresis voltage ($V_{T+} - V_{T-}$) | $V_{CC} = 1.2\text{ V}$ | 0.1 | 1.0 | 0.1 | 1.0 | V |
| | | $V_{CC} = 1.65\text{ V}$ | 0.2 | 1.15 | 0.2 | 1.15 | V |
| | | $V_{CC} = 1.95\text{ V}$ | 0.2 | 1.25 | 0.2 | 1.25 | V |
| | | $V_{CC} = 2.3\text{ V}$ | 0.3 | 1.3 | 0.3 | 1.3 | V |
| | | $V_{CC} = 2.5\text{ V}$ | 0.3 | 1.3 | 0.3 | 1.3 | V |
| | | $V_{CC} = 2.7\text{ V}$ | 0.3 | 1.1 | 0.3 | 1.1 | V |
| | | $V_{CC} = 3.0\text{ V}$ | 0.3 | 1.2 | 0.3 | 1.2 | V |
| | | $V_{CC} = 3.6\text{ V}$ | 0.3 | 1.2 | 0.3 | 1.2 | V |
| | | $V_{CC} = 4.5\text{ V}$ | 0.4 | 0.77 | 0.34 | 0.77 | V |
| | | $V_{CC} = 5.5\text{ V}$ | 0.47 | 0.88 | 0.41 | 0.88 | V |

11.1. Waveforms transfer characteristics



12. Package Outline

SOP-14L

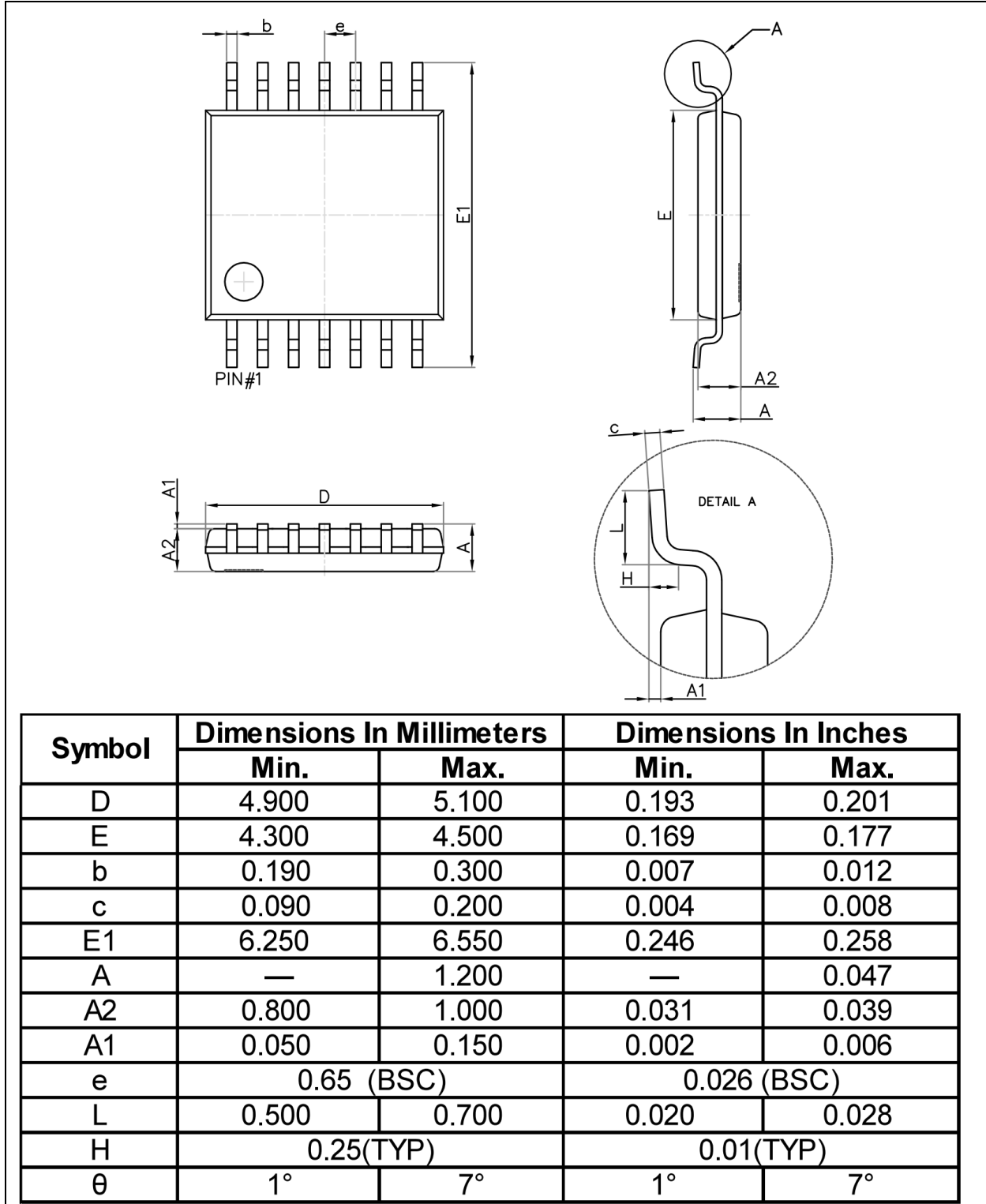


| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | — | 1.750 | — | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.250 | — | 0.049 | — |
| b | 0.310 | 0.510 | 0.012 | 0.020 |
| c | 0.100 | 0.250 | 0.004 | 0.010 |
| D | 8.450 | 8.850 | 0.333 | 0.348 |
| E | 5.800 | 6.200 | 0.228 | 0.244 |
| E1 | 3.800 | 4.000 | 0.150 | 0.157 |
| e | 1.270(BSC) | | 0.050(BSC) | |
| L | 0.400 | 1.270 | 0.016 | 0.050 |
| θ | 0° | 8° | 0° | 8° |

EM74LVC14A

Hex inverting Schmitt trigger with 5 V tolerant input

TSSOP-14L



13. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal-Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| CDM | Charged Device Model |
| TTL | Transistor-Transistor Logic |

14. Revision History

Table 12. Revision history

| Document ID | Release Date | Data sheet status | Change notice | Supersedes |
|---------------------|--|-------------------|---------------|---------------------|
| EM74LVC14A Rev. 1.2 | Jul 29, 2025 | Product datasheet | | EM74LVC14A Rev. 1.1 |
| Modifications: | <ul style="list-style-type: none"> Section 3 updated: Added marking information. | | | |
| EM74LVC14A Rev. 1.1 | Aug 30, 2024 | Product datasheet | | EM74LVC14A Rev. 1.0 |
| Modifications: | <ul style="list-style-type: none"> Table 6: V_{OH} and V_{OL} updated. Table 7: t_{pd} and C_{pd} updated. | | | |
| EM74LVC14A Rev. 1.0 | Oct 30, 2023 | Product datasheet | | |